

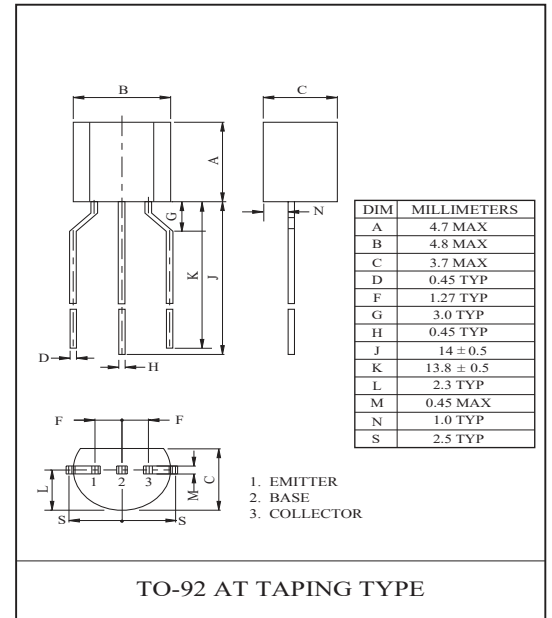
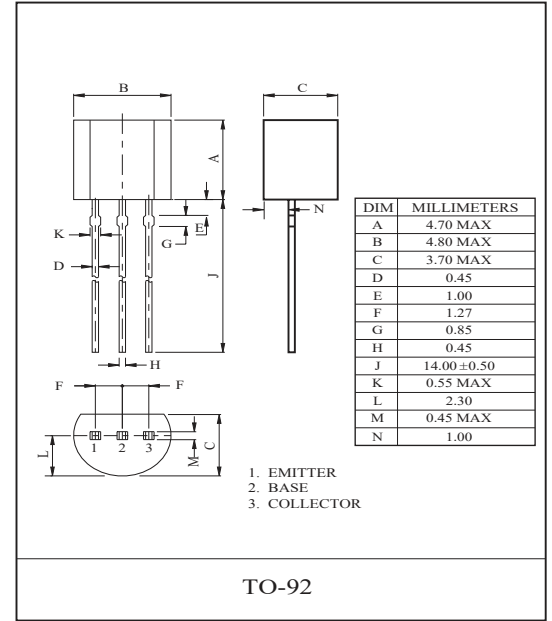
GENERAL PURPOSE APPLICATION.
SWITCHING APPLICATION.

FEATURES

- Excellent h_{FE} Linearity.
: $h_{FE}(I_C=0.1mA)/h_{FE}(I_C=2mA)=0.95(Typ.)$
- Low Noise : $NF=1dB(Typ.)$. at $f=1kHz$
- Complementary to KTA733B(O, Y, GR class).

MAXIMUM RATING (Ta=25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CBO}	60	V
Collector-Emitter Voltage	V_{CEO}	50	V
Emitter-Base Voltage	V_{EBO}	5	V
Collector Current	I_C	150	mA
Collector Power Dissipation	P_C	625	mW
Junction Temperature	T_j	150	°C
Storage Temperature Range	T_{stg}	-55 ~ 150	°C



ELECTRICAL CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=100\mu A, I_E=0$	60	-	-	V
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=1mA, I_B=0$	50	-	-	V
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=100\mu A, I_C=0$	5	-	-	V
Collector Cut-off Current	I_{CBO}	$V_{CB}=60V, I_E=0$	-	-	0.1	μA
Emitter Cut-off Current	I_{EBO}	$V_{EB}=5V, I_C=0$	-	-	0.1	μA
DC Current Gain	h_{FE} (Note)	$V_{CE}=6V, I_C=2mA$	70	-	700	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=100mA, I_B=10mA$	-	0.1	0.25	V
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=100mA, I_B=10mA$	-	-	1.0	V
Transition Frequency	f_T	$V_{CE}=10V, I_C=10mA$	-	300	-	MHz
Collector Output Capacitance	C_{ob}	$V_{CB}=10V, I_E=0, f=1MHz$	-	2.0	3.5	pF
Noise Figure	NF	$V_{CE}=6V, I_C=0.1mA, R_g=10k\Omega, f=1kHz$	-	1.0	10	dB

Note : h_{FE} Classification O:70~140, Y:120~240, GR:200~400, BL:350~700

KTC945B

